

DESCRIPTION

The MJD31C is available in TO-252 package.

APPLICATION

• Linear and Switching Industrial Application

ORDERING INFORMATION

Package Type	Part Number	
TO-252	MJD31C	
SPQ	2,500pcs/Reel	
AiT provides all RoHS Compliant Products		

FEATURE

Complementary to MJD32C

PIN DESCRIPTION



TO-252

PIN#	DESCRIPTION		
1	BASE		
2, 4	COLLECTOR		
3	EMITTER		

ABSOLUTE MAXIMUM RATINGS

Ta= 25°C, unless otherwise specified.		
BV _{CBO} , Collector-Base Voltage	100V	
BV _{CEO} , Collector-Emitter Voltage	100V	
BV _{EBO} , Emitter-Base Voltage	5V	
I _C , Collector Current (DC)		3A
I _{см} , Collector peak current		5A
D. Collector Dissignation	T _a = 25°C	2W
Pc, Collector Dissipation	T _a = 100°C	40W
T _J , Operating Temperature Range		-65℃ ~ + 150℃
T _{STG} , Storage Temperature Range		-65°C ~ + 150°C

Stresses above may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other conditions beyond those indicated in the Electrical Characteristics are not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.



ELECTRICAL CHARACTERISTICS

 $T_A=25^{\circ}C$ unless otherwise specified.

Parameter	Symbol	Condition	Min	Тур.	Мах	Unit
Collector-Emitter Sustaining Voltage	$V_{CEO(sus)}$	Ic=300mA,	100	-	-	V
		I _B =0				V
	Iceo	Vce=60V,	-	-	0.30	mA
		I _E =0				
	I _{EBO}	V _{EB} =5V,	-	-	1	mA
		I _E =0				
	Ices	V _{CE} =100V,	-	-	0.20	mA
		V _{EB} =0				
DC Current Gain *	hfe	V _{CE} =4V,	25	-	50	
		Ic=1A				
		V _{CE} =4V,	10	-	-	_
		Ic=3A				
Collector-Emitter Saturation Voltage*	V _{CE(sat)}	Ic=3A,	-	-	1.20	V
		I _B =375mA				V
Base-Emitter ON Voltage*	$V_{BE(on)}$	V _{CE} =4V,	-	-	1.80	V
		I _C =3A				
Current Gain Bandwidth Product*	f⊤	V _{CE} =10V,	3	-	-	
		Ic=500mA				



TYPICAL CHARACTERISTICS

Fig 1. DC Current Gain



Fig 3. Collector Capacitance



Fig 5. Turn Off Time



Fig 2. Base-Emitter Saturation Voltage Collector-Emitter Saturation Voltage







Fig 6. Turn On Time





PACKAGE INFORMATION

Dimension in TO-252 (Unit: mm)







	MILLIMETERS			
STMBOL	Min.	Max.		
А	2.200	2.500		
A1	0.000	0.120		
A2	2.200	2.400		
В	1.200	1.600		
b	0.500	0.700		
b1	0.700	0.900		
С	0.400	0.600		
c1	0.400	0.600		
D	6.350	6.650		
D1	5.200	5.400		
Е	5.400	5.700		
е	2.200	2.400		
e1	4.400	4.800		
L	10.000	11.000		
L1	2.700	3.100		
L2	1.400	1.800		
L3	0.900	1.500		



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